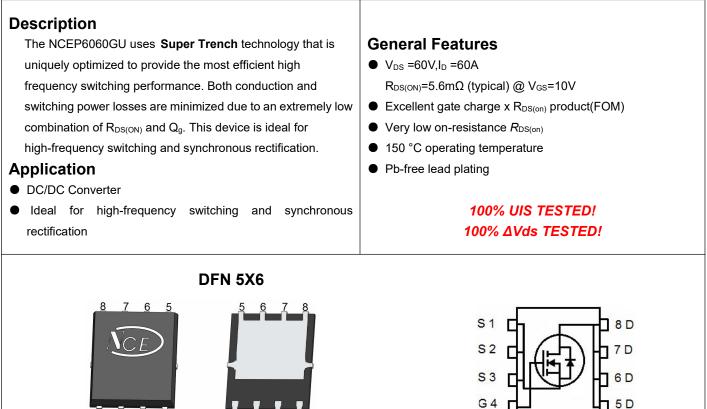
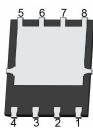


NCE N-Channel Super Trench Power MOSFET



Schematic Diagram





Top View

Bottom View

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P6060GU	NCEP6060GU	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (Silicon Limited)	Ι _D	60	A
Drain Current-Continuous(Tc=100°C)	I _D (100℃)	42.4	Α
Pulsed Drain Current	I _{DM}	170	A
Maximum Power Dissipation	PD	70	W
Derating factor		0.56	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	320	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C
Thermal Characteristic		·	·
Thermal Resistance, Junction-to-Case ^(Note 2)	R _{θJC}	1.78	°C/W
Thermal Resistance, Junction-to-Ambient ^(Note 2)	R _{0JA}	50	°C/W



Electrical Characteristics (Tc=25 $^\circ\!\mathrm{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· · ·		•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	60		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =10V, I_{D} =20A	-	5.6	7.0	mΩ
Forward Transconductance	g fs	V_{DS} =5V,I _D =20A	35	-	-	S
Dynamic Characteristics (Note4)	. I		·			
Input Capacitance	Clss	V _{DS} =30V,V _{GS} =0V,	-	1700	-	PF
Output Capacitance	Coss		-	345	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	8	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =30V,I _D =20A V _{GS} =10V,R _G =4.7Ω	-	8	-	nS
Turn-on Rise Time	tr		-	2	-	nS
Turn-Off Delay Time	t _{d(off)}		-	29	-	nS
Turn-Off Fall Time	t _f		-	4	-	nS
Total Gate Charge	Qg	V _{DS} =30V,I _D =20A, V _{GS} =10V	-	26.9		nC
Gate-Source Charge	Q _{gs}		-	9.4		nC
Gate-Drain Charge	Q _{gd}		-	4.6		nC
Drain-Source Diode Characteristics			· ·			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V
Diode Forward Current (Note 2)	ls		-	-	60	A
Reverse Recovery Time	trr	$T_J = 25^{\circ}C, I_F = I_S$	-	38		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	48		nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in2 FR-4 board with 2oz. Copper, in a still air environment with T_A =25° C. The the maximum allowed junction temperature of 150° C

3. Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.

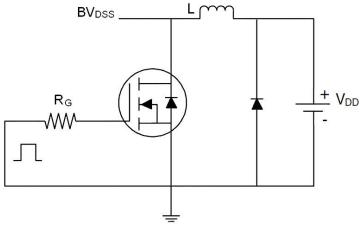
4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \rm C$,V_DD=30V,V_G=10V,L=0.5mH,Rg=25\Omega

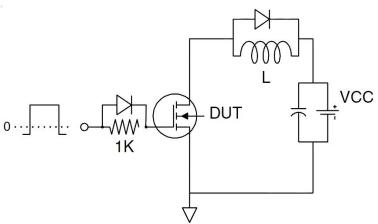


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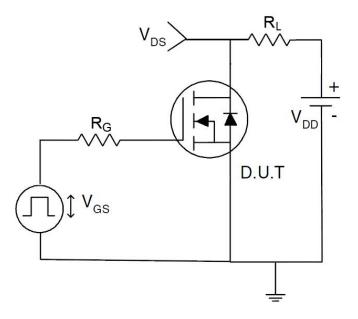
Test Circuit 1) E_{AS} test Circuit



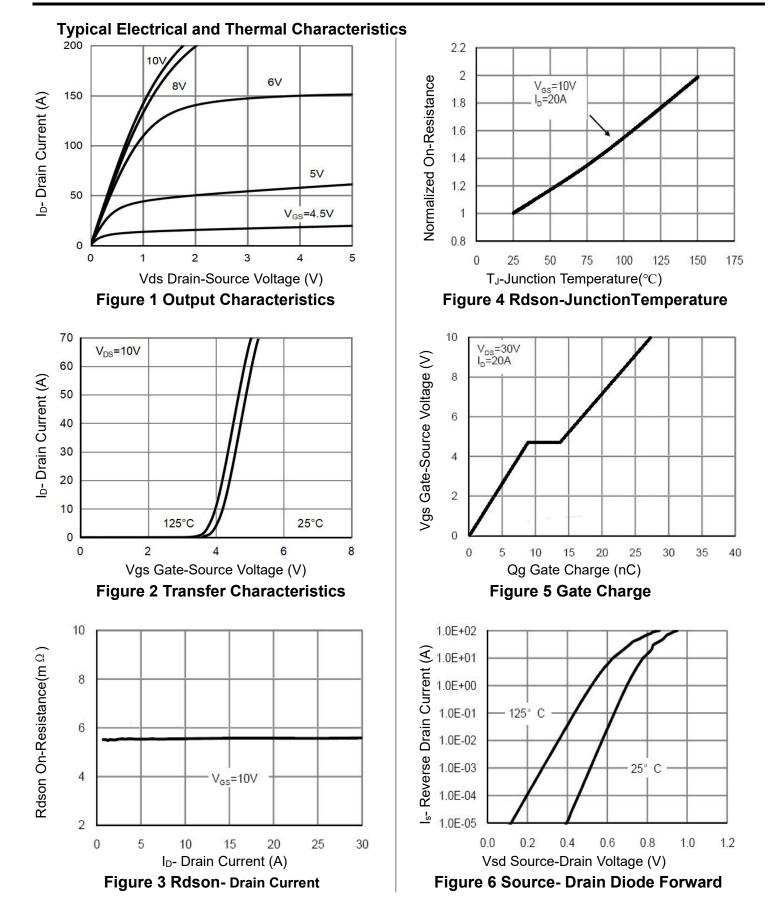
2) Gate charge test Circuit



3) Switch Time Test Circuit



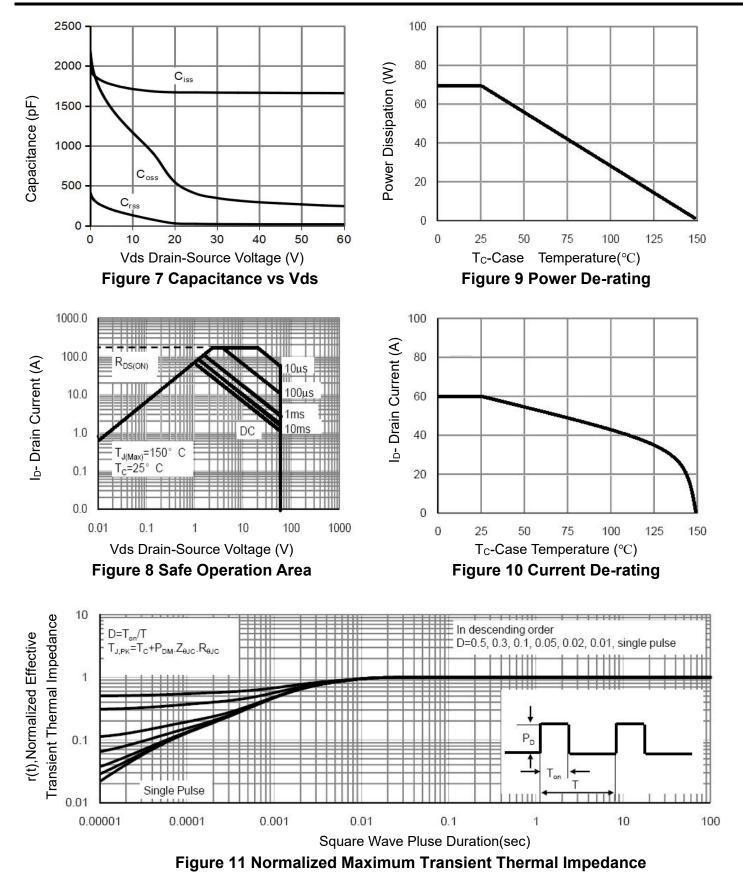






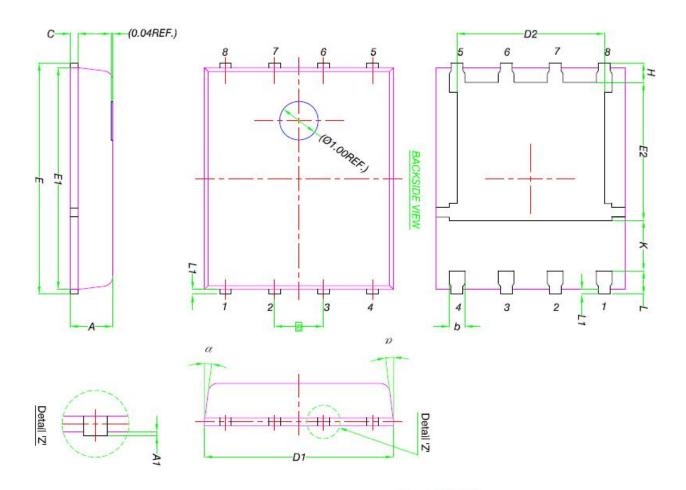
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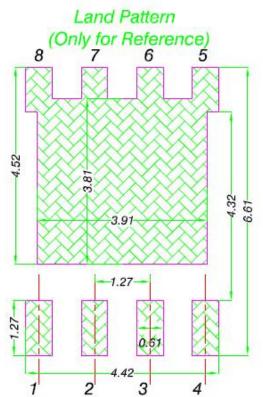




DFN5X6-8L Package Information



-	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
A	0.90	1.00	1.10	
A1	0	-	0.05	
b	0.33	0.41	0.51	
С	0.20	0.25	0.30	
D1	4.80	4.90	5.00	
D2	3.61	3.81	3.96	
Ε	5.90	6.00	6.10	
E1	5.70	5.75	5.80	
E2	3.38	3.58	3.78	
е		1.27 BSC	8	
Н	0.41	0.51	0.61	
К	1.10			
L	0.51	0.61	0.71	
L1	0.06	0.13	0.20	
α	0°	-	12	





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